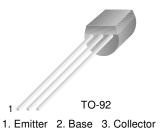
FAIRCHILD

SEMICONDUCTOR®

KSC815

Low Frequency Amplifier & High Frequency Oscillator

- Collector-Base Voltage : V_{CBO}=60V
- Complement to KSA539
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^{\circ}C$ unless otherwise noted

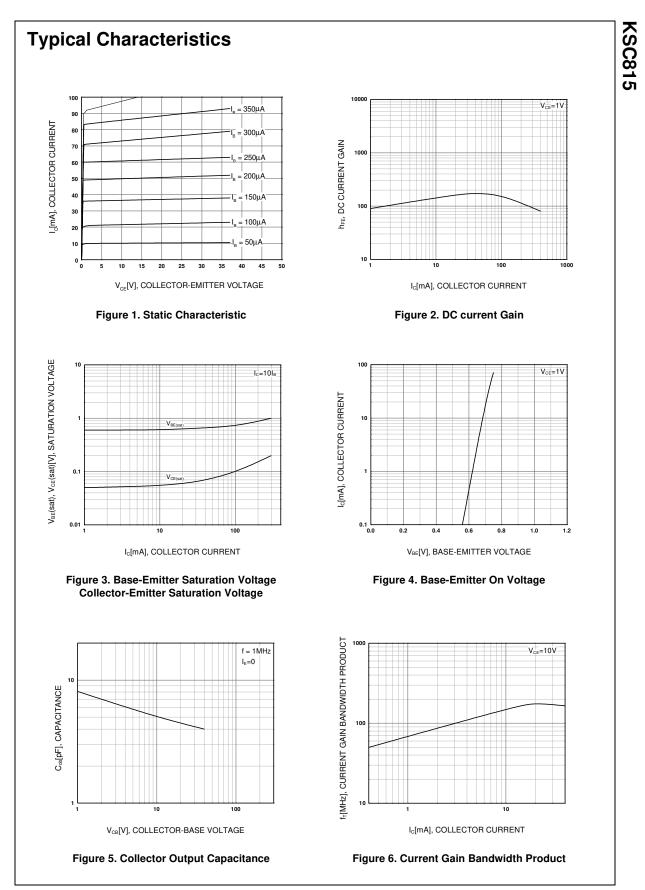
Symbol	Parameter	Value	
V _{CBO}	Collector-Base Voltage	60	V
V _{CEO}	Collector-Emitter Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	200	mA
P _C	Collector Power Dissipation	400	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics $T_a=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =100μA, I _E =0	60			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	45			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μA, I _C =0	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =45V, I _E =0			0.1	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} =3V, I _C =0			0.1	μA
h _{FE}	DC Current Gain	V _{CE} =1V, I _C =50mA	40		400	
V_{BE} (on)	Base-Emitter On Voltage	V _{CE} =10V, I _C =10mA	0.6	0.65	0.9	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =150mA, I _B =15mA		0.15	0.4	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =150mA, I _B =15mA		0.83	1.1	V
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =10mA	100	200		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		4		pF

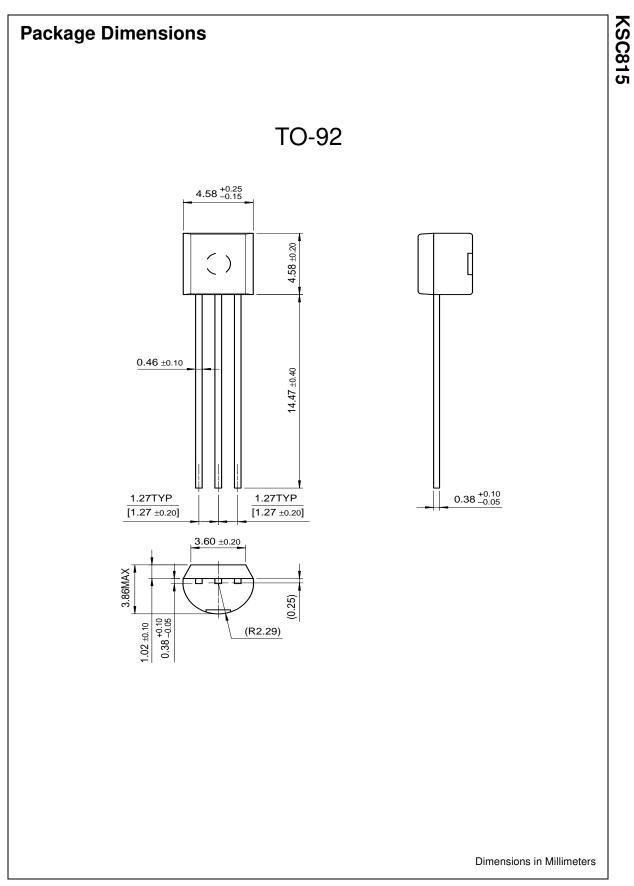
h_{FE} Classification

Classification	R	0	Y	G			
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240	200 ~ 400			



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Rev. A2, September 2002



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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